

LCP1531

ASD (Application Specific Devices)

Programmable transient voltage suppressor for SLIC protection

Features

- Dual programmable transient suppressor
- Wide negative firing voltage range: V_{MGL} = -150 V max.
- Low dynamic switching voltages: V_{FP} and V_{DGI}
- Low gate triggering current: I_{GT} = 5 mA max
- Peak pulse current: $I_{PP} = 37.5 \text{ A} (5/310 \text{ µs})$
- Holding current: I_H = 150 mA min
- Low space consuming package

Description

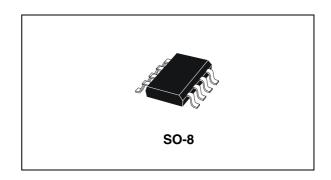
These devices have been especially designed to protect new high-voltage, as well as classical SLICs, against transient overvoltage.

Positive overvoltages are clamped by 2 diodes. Negative surges are suppressed by 2 thyristors, their breakdown voltage being referenced to - V_{BAT} through the gate.

These components present a very low gate triggering current (I_{GT}) in order to reduce the current consumption on printed circuit board during the firing phase.

Benefits

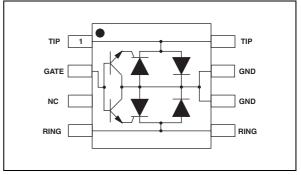
TRISILs™ are not subject to ageing and provide a fail-safe mode in short circuit for better protection. They are used to help equipment to meet various standards such as YDT695, and ITU-T K20/21. TRISILs are UL94 V0 resin approved and are UL497B approved [file: E136224]).



Order code

Part Number	Marking
LCP1531RL	CP153

Figure 1. LCP1531 Functional Diagram



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Characteristics LCP1531

1 Characteristics

Table 1. Compliance with the following Standards

Standard	Peak surge voltage (V)	Voltage waveform	Required peak current (A)	Current waveform	Minimum serial resistor to meet standard (Ω)
YDT695, ITU-T-K20/K21	1500	10/700 μs	37.5	5/310 µs	0
ITU-T-K20 (IEC 61000-4-2)	8000 15000	1-60 ns	ESD contact discharge ESD air discharge		0 0

 Table 2.
 Thermal Resistance

Symbol	Parameter	Value	Unit
R _{th(j-a)}	Junction to ambient	120	° C/W

Table 3. Electrical Characteristics ($T_{amb} = 25^{\circ} C$)

Symbol	Parameter	A I
I _{GT}	Gate triggering current	Ţ.
Ι _Η	Holding current	
I _{RM}	Reverse leakage current LINE / GND	
I _{RG}	Reverse leakage current GATE / LINE	
V_{RM}	Reverse voltage LINE / GND	VR VRM /VF
V _{GT}	Gate triggering voltage	→V
V _F	Forward drop voltage LINE / GND	IR
V _{FP}	Peak forward voltage LINE / GND	\ IH
V_{DGL}	Dynamic switching voltage GATE / LINE	I PP
V _{RG}	Reverse voltage GATE / LINE	
С	Capacitance LINE / GND	'

LCP1531 Characteristics

Table 4. Absolute ratings ($T_{amb} = 25^{\circ} C$, unless otherwise specified)

Symbol	Parameter	Value	Unit	
I _{PP}	Peak pulse current	5/310 μs	37.5	Α
I _{TSM}	Non-repetitive surge peak on-state current (50Hz sinusoidal)		16 9 6	Α
I _{GSM}	Maximum gate current (50Hz sinusoidal) t = 10ms		2	Α
V _{MLG} V _{MGL}	Maximum voltage LINE/GND Maximum voltage GATE/LINE	-150 -150	٧	
T _{stg} T _j	Storage temperature range Maximum junction temperature	-55 to +150 150	° C	
TL	Maximum lead temperature for soldering du	ring 10 s.	260	° C

Table 5. Repetitive peak pulse current

Symbol	Definition	Example
t _r	Rise time (µs)	Pulse waveform
t _p	Pulse duration (μs)	5/310 μ s: $t_r = 5 \mu$ s $t_p = 310 \mu$ s

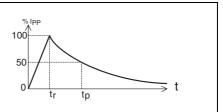


Table 6. Parameters related to the diode LINE / GND ($T_{amb} = 25^{\circ} C$)

Symbol		Test conditions		Max	Unit
V _F	I _F = 5A		t = 500 μs	3	V
V _{FP} ⁽¹⁾	10/700 μs	V _{PP} = 1.5 kV	$R_S = 15 \Omega$	5	V

^{1.} see test circuit for $V_{\mbox{FP}}$; RS is the protection resistor located on the line card.

Table 7. Parameters related to the protection Thyristors ($T_{amb} = 25^{\circ} C$)

Symbol	Test conditions	Min	Max	Unit
I _{GT}	V _{GND / LINE} = -48 V	0.1	5	mA
I _H	$V_{GATE} = -48 V^{(1)}$	150		mA
I _{RG}	V _{RG} = -75 V		5	μΑ
V	$V_{GATE} = -48 \ V^{(2)}$			
V _{DGL}	10/700 μs V_{PP} = 1.5 kV R_{S} = 15 Ω I_{PP} = 27.5 A		7	V

 $^{1. \}quad \text{see functional holding current (I$_H$) test circuit} \\$

 $^{2. \}quad \text{see test circuit for $V_{\hbox{\scriptsize DGL}}$ The oscillations with a time duration lower than 50 ns are not taken into account.}$

Technical information LCP1531

Table 8. Parameters related to diode and protection Thyristors (Tamb = 25° C, unless otherwise specified)

Symbol	Test conditions		Тур	Max	Unit
I _{RM}	$V_{GATE / LINE} = -1 V V_{RM} = -75 V$	T _j = 25° C		5	μΑ
С	$V_R = 50 \text{ V bias}, V_{RMS} = 1 \text{ V}, F = 1 \text{ MHz}$ $V_R = 2 \text{ V bias}, V_{RMS} = 1 \text{ V}, F = 1 \text{ MHz}$		15 35		pF

2 Technical information

Figure 2. Functional holding current (I_H) test circuit: GO-NO GO test

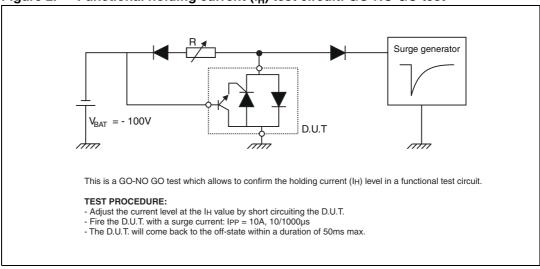
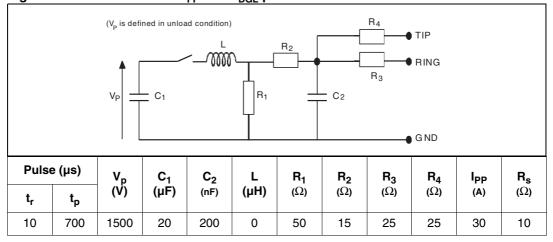


Figure 3. Test circuit for V_{FP} and V_{DGL} parameters



LCP1531 Technical information

Figure 4. LCP1531 concept behavior

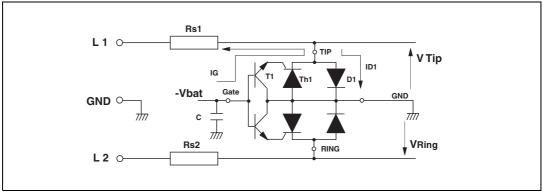


Figure 4. shows the classical protection circuit using the LCP1531 crowbar concept. This topology has been developed to protect the new high voltage SLICs. It allows to program the negative firing threshold while the positive clamping value is fixed at GND.

When a negative surge occurs on one wire (L1 for example) a current IG flows through the base of the transistor T1 and then injects a current in the gate of the thyristor Th1. Th1 fires and all the surge current flows through the ground. After the surge when the current flowing through Th1 becomes less negative than the holding current IH, then Th1 switches off.

When a positive surge occurs on one wire (L1 for example) the diode D1 conducts and the surge current flows through the ground.

Figure 5. Example of PCB layout based on LCP1531 protection

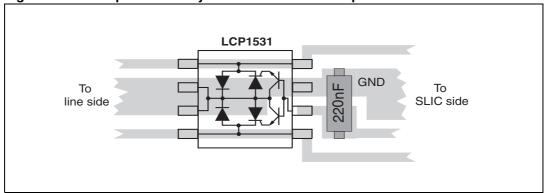


Figure 5. shows the classical PCB layout used to optimize line protection.

The capacitor C is used to speed up the crowbar structure firing during the fast surge edges.

This allows to minimize the dynamical breakover voltage at the SLIC Tip and Ring inputs during fast strikes. Note that this capacitor is generally present around the SLIC - Vbat pin.

So to be efficient it has to be as close as possible from the LCP1531 Gate pin and from the reference ground track (or plan) (see *Figure 5*.). The optimized value for C is 220 nF.

The series resistors Rs1 and Rs2 designed in *Figure 4.* represent the fuse resistors or the PTC which are mandatory to withstand the power contact or the power induction tests imposed by the various country standards. Taking into account this fact the actual lightning surge current flowing through the LCP1531 is equal to:

Technical information LCP1531

$$I_{surge} = V_{surge} / (R_g + R_s)$$

With:

 V_{surge} = peak surge voltage imposed by the standard.

 R_{α} = series resistor of the surge generator

R_s = series resistor of the line card (e.g. PTC)

The LCP1531 is particularly optimized for the new telecom applications such as the fiber in the loop, the WLL, the remote central office. In this case, the operating voltages are smaller than in the classical system. This makes the high voltage SLICs particularly suitable.

The schematics of *Figure 6*. gives the most frequent topology used for these applications.

Figure 6. Protection of high voltage SLIC

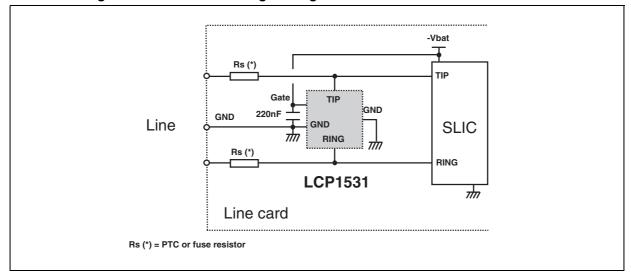
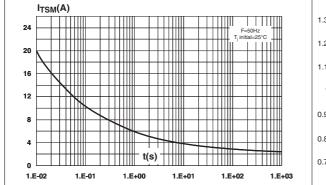
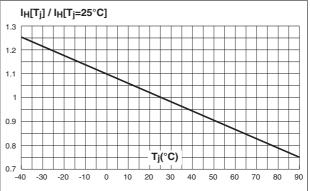


Figure 7. Surge peak current versus overload duration

Figure 8. Relative variation of holding current versus junction temperature





6/9

LCP1531 Package information

3 Package information

Epoxy meets UL94, V0

Table 9. SO-8 dimensions

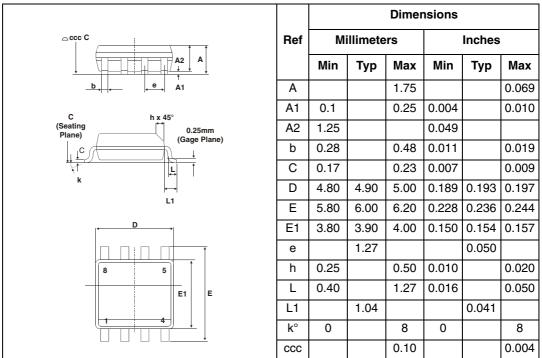
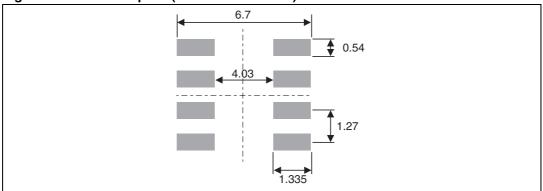


Figure 9. SO-8 footprint (dimensions in mm)



In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

5/

Ordering information LCP1531

4 Ordering information

Part Number	Marking	Package	Weight	Base qty	Delivery mode
LCP1531RL	CP153	SO-8	0.08 g	2500	Tape and reel

5 Revision history

Date	Revision	Description of Changes
31-Mar-2007	1	First issue.

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